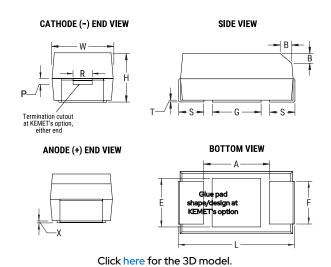


## T495B685K010ATA1K1

T495 Auto, Tantalum, MnO2 Tantalum, Commercial Grade, 6.8 uF, 10%, 10 VDC, SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200, 1.1 Ohms, 3528, 2.1 mm, 0.8 mm



T495 Auto
MnO2 Tantalum
SMD Chip
SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200
Low ESR, Automotive
Yes
Tin
AEC-Q200
Yes
107.45 mg

Dimensions	
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +0.1/-0.3mm
F	2.2mm +/-0.1mm
A	1.9mm MIN
В	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
Р	0.5mm REF
R	1mm REF
Х	0.1mm +/-0.1mm REF

Specifications	
Capacitance	6.8 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	1100 mOhms (100kHz 25C)
Ripple Current	278 mA (rms, 100kHz 25C), 250.2 mA (rms, 85C), 111.2 mA (rms, 125C)
Leakage Current	0.7 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

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